

# PHILIPS

sense **and** simplicity

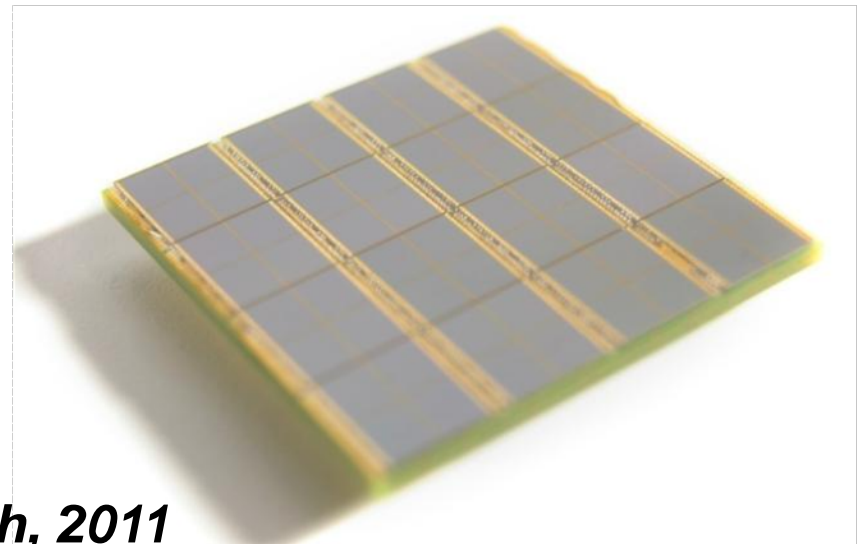
## Photon Counting with arrays of Digital SiPM's

*Philips Digital Photon Counting  
(PDPC)*

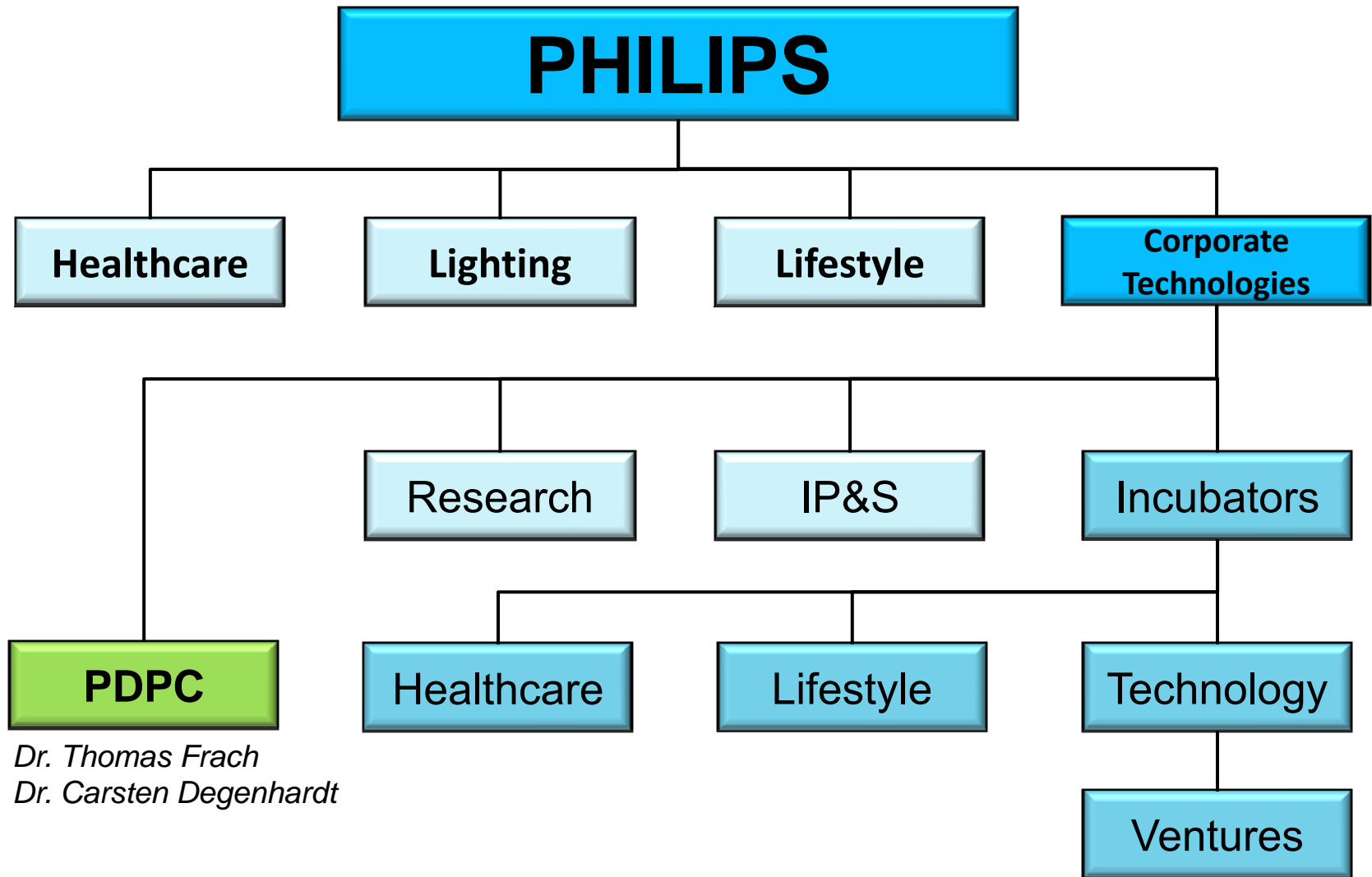
*Dr. York Hämisch*

*Anja Schmitz*

*SiPM event, CERN, February 17th, 2011*



# *PDPC in Philips*



*Dr. Thomas Frach*  
*Dr. Carsten Degenhardt*

# ***Digital Silicon Photomultipliers (dSiPM) - The next solid state innovation***

**Transistor**



**Television**



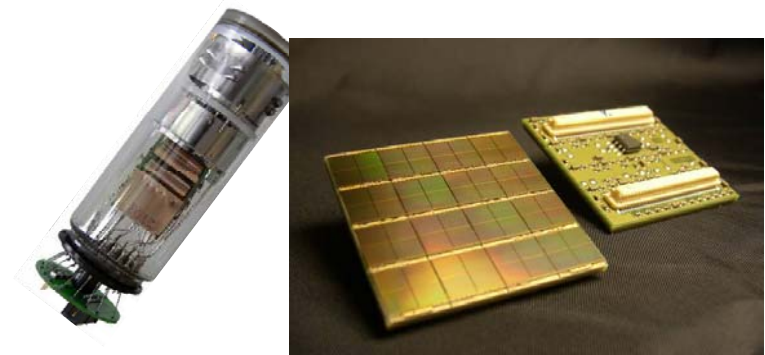
**Digital Camera**



**X-Ray imaging**

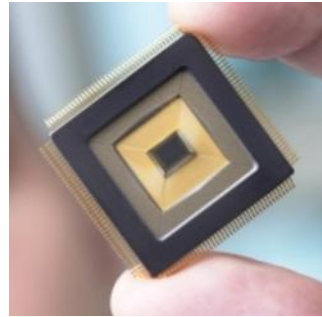


**Digital Photon Counting**

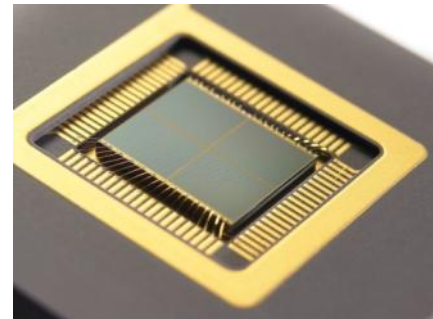


# *How to replace old-fashioned PMT's?*

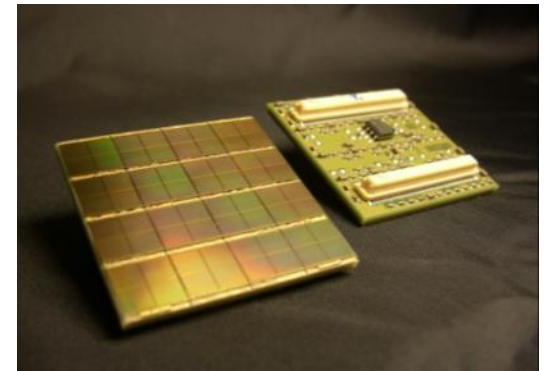
- Make the SiPM digital
  - 1 pixel



- Increase integration
  - 2 x 2 pixel on one chip (die)



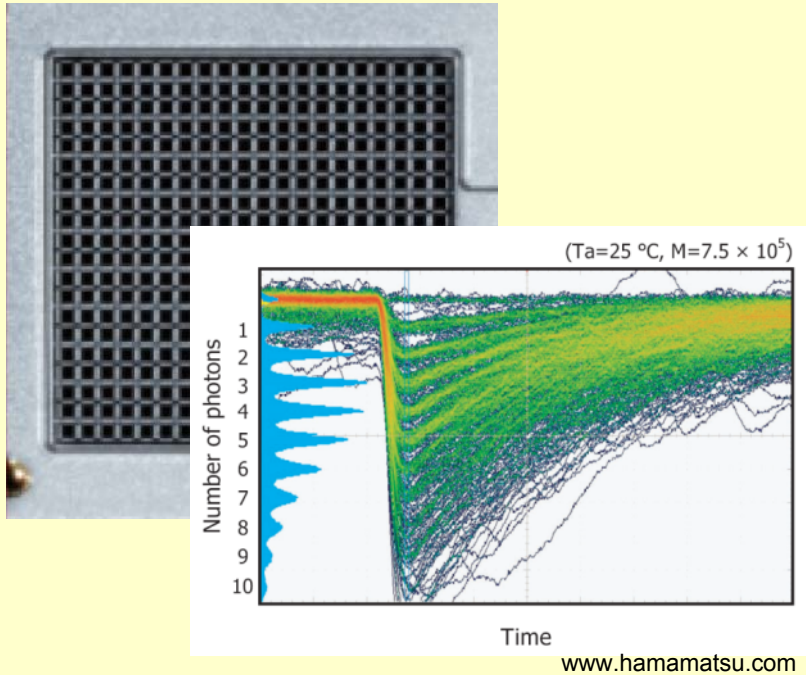
- Assemble arrays
  - 8 x 8 pixels on one PCB (tile)



# Digital Photon Counting – The concept

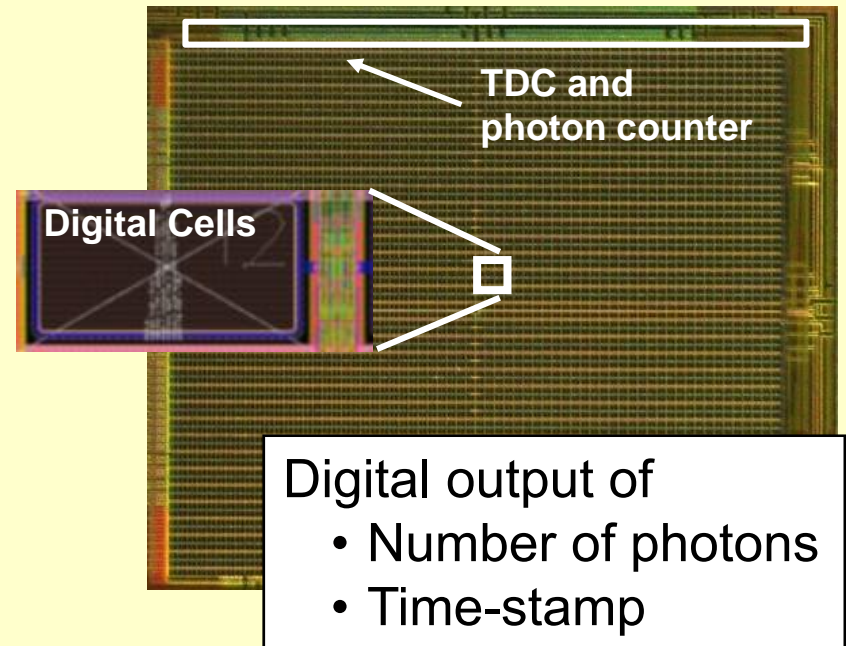
Intrinsically, the SiPM is a digital device: a single cell breaks down or not

## analog SiPM



Summing all cell outputs leads to an analog output signal and limited performance

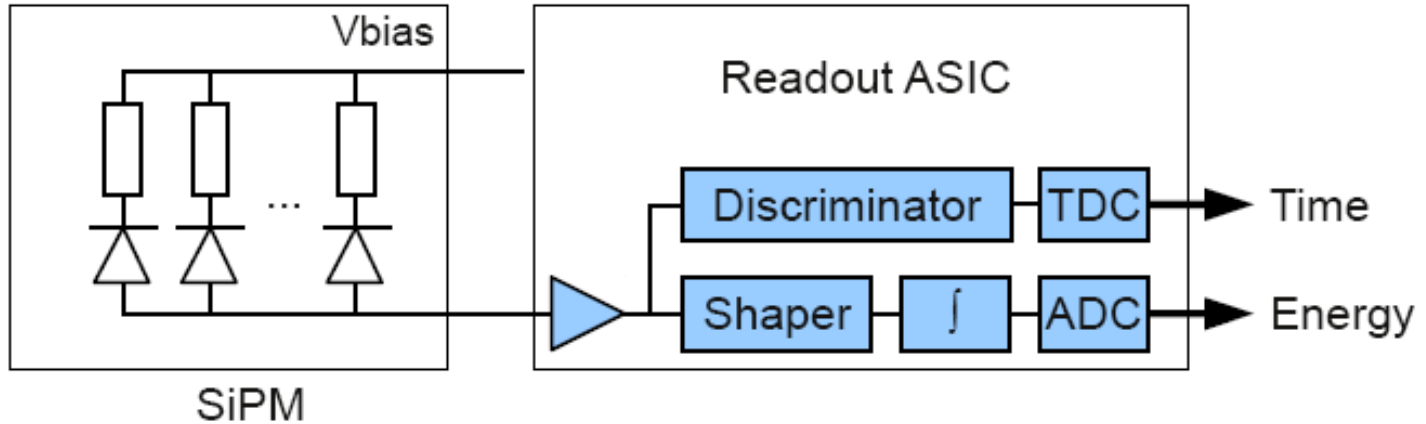
## digital SiPM (dSiPM)



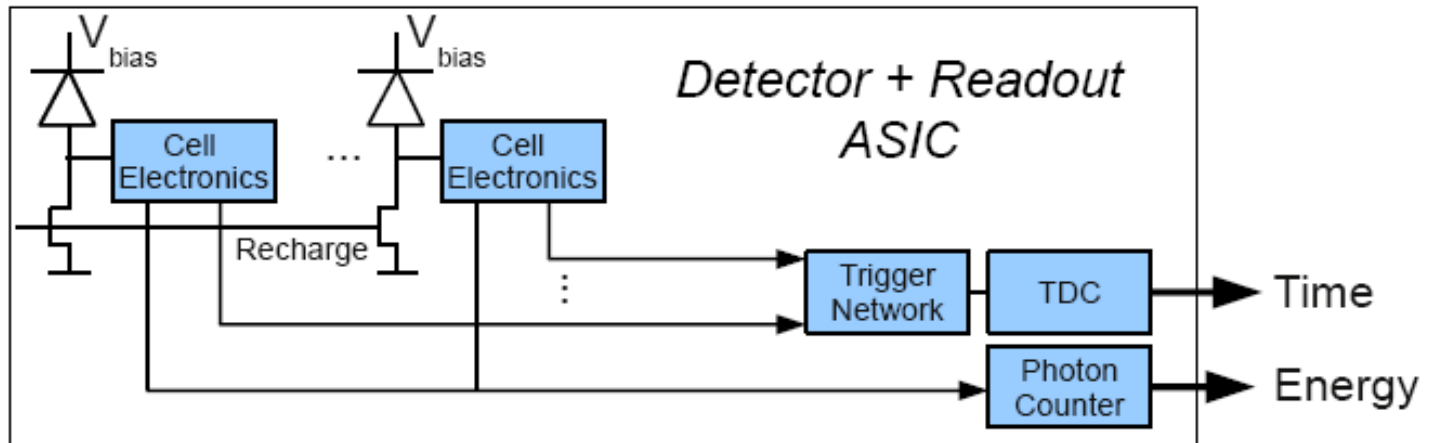
Integrated readout electronics is the key element to superior detector performance

# Analog vs. Digital SiPM

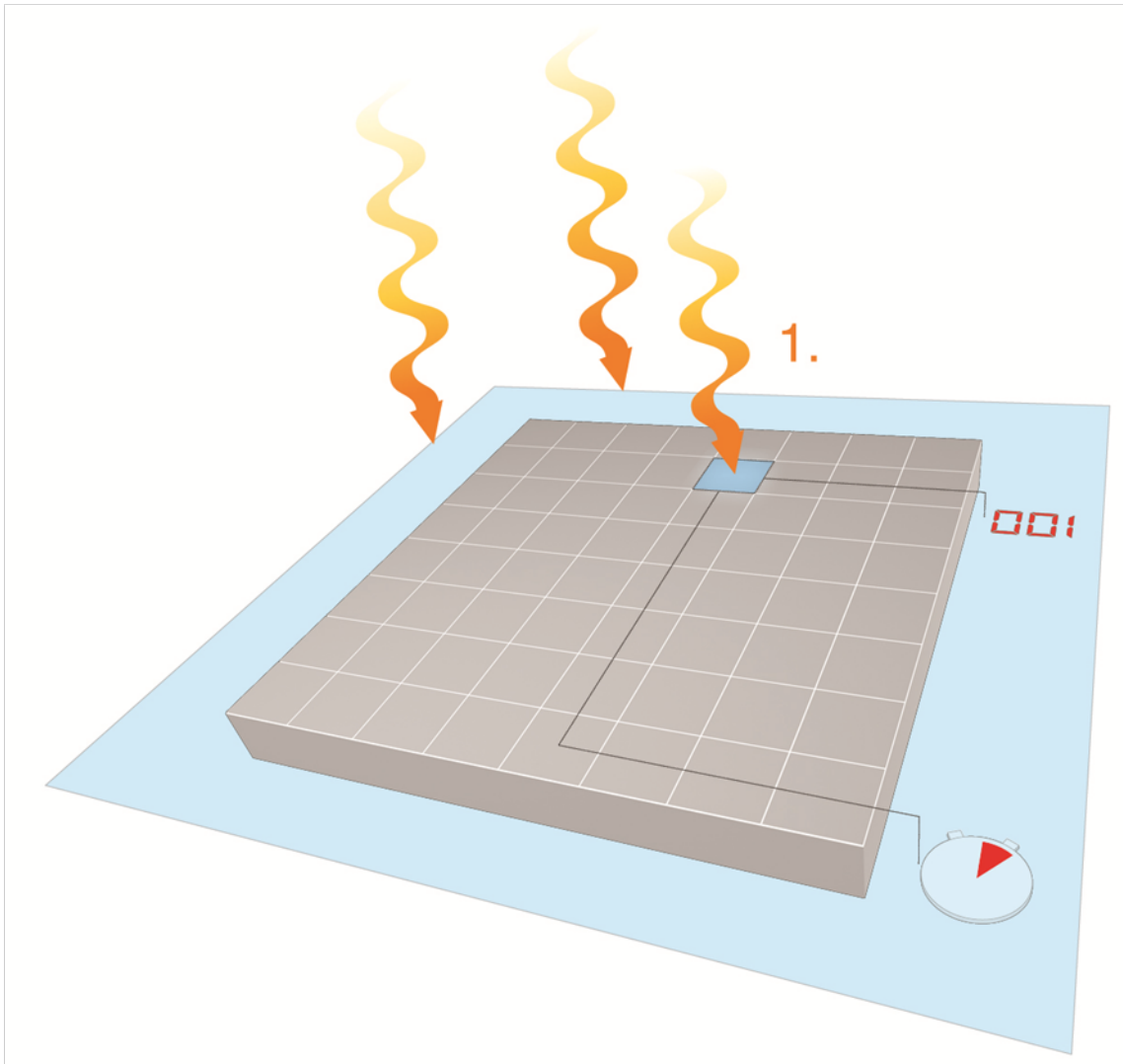
*Analog Silicon Photomultiplier Detector*



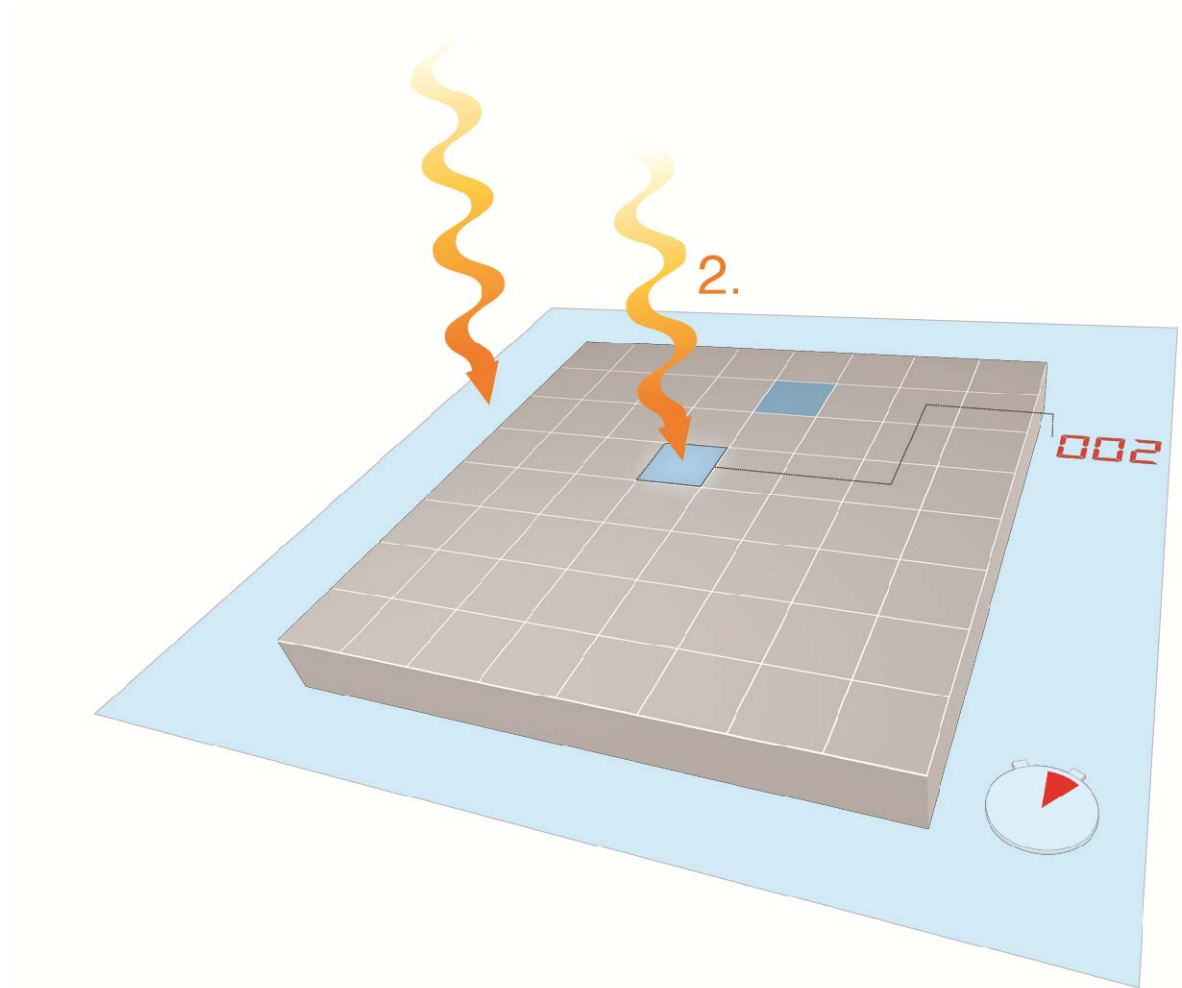
*Digital Silicon Photomultiplier Detector*



# Digital SiPM: Principle

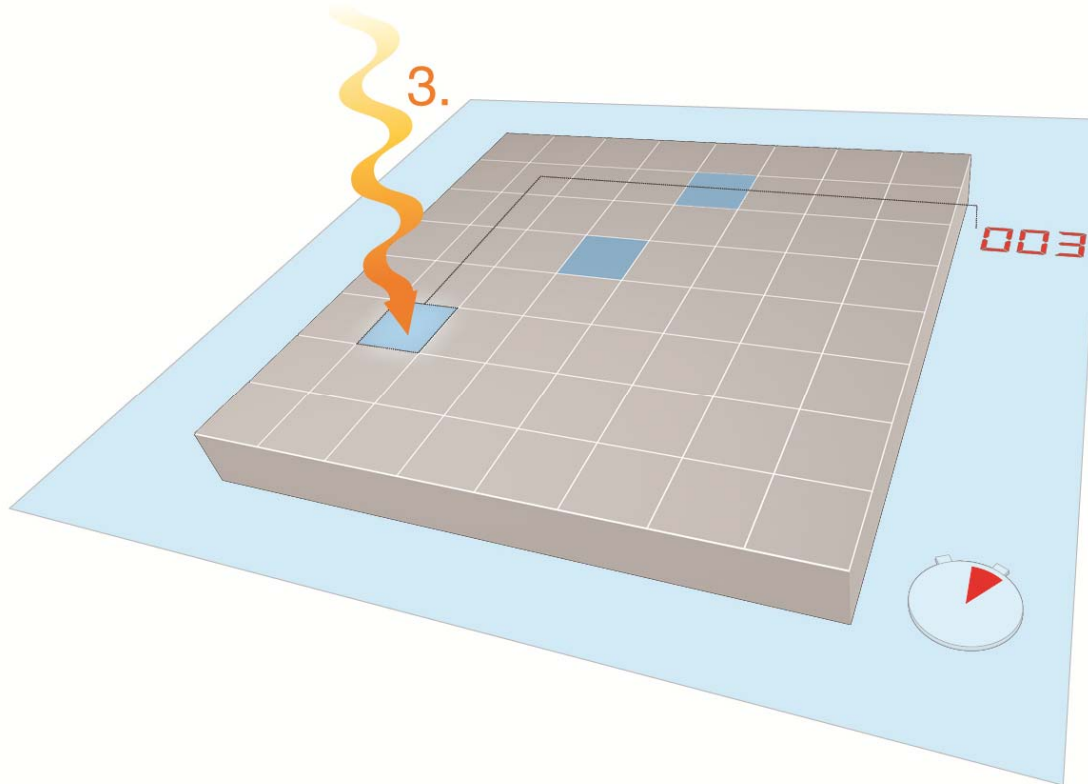


# Digital SiPM: Principle

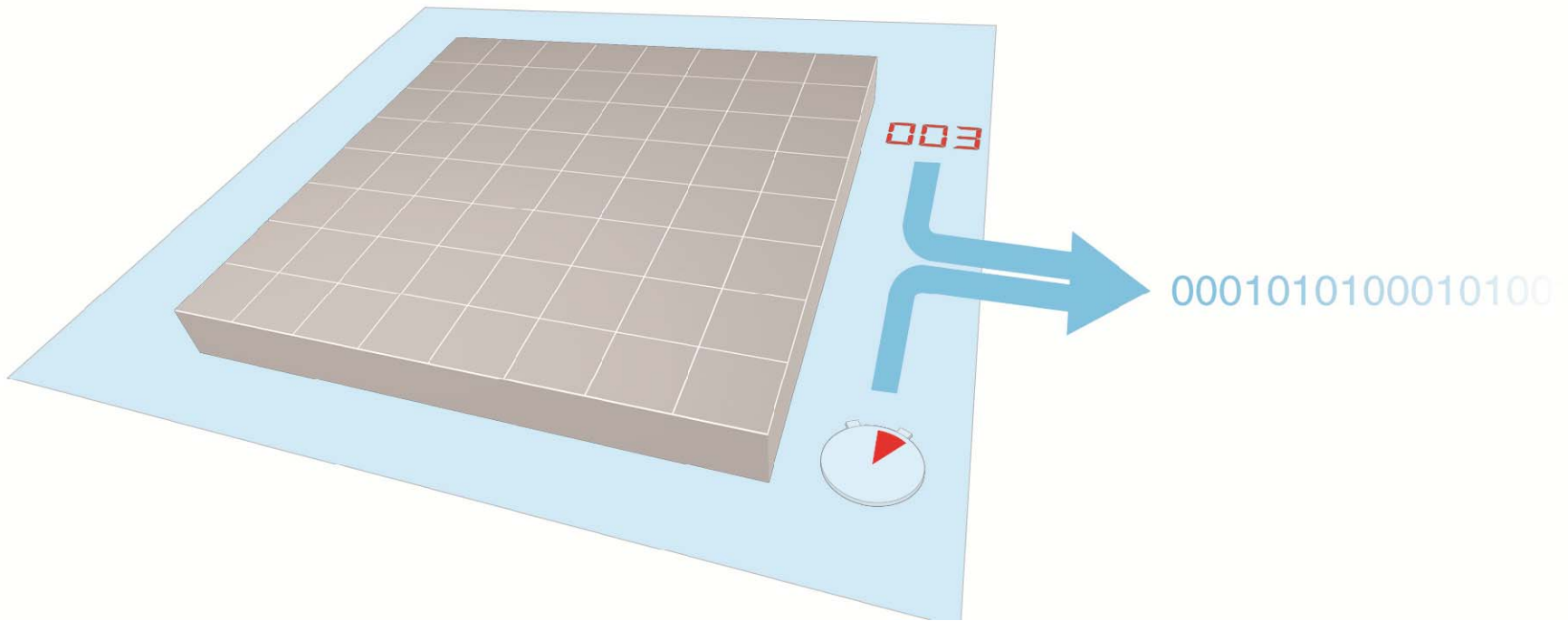




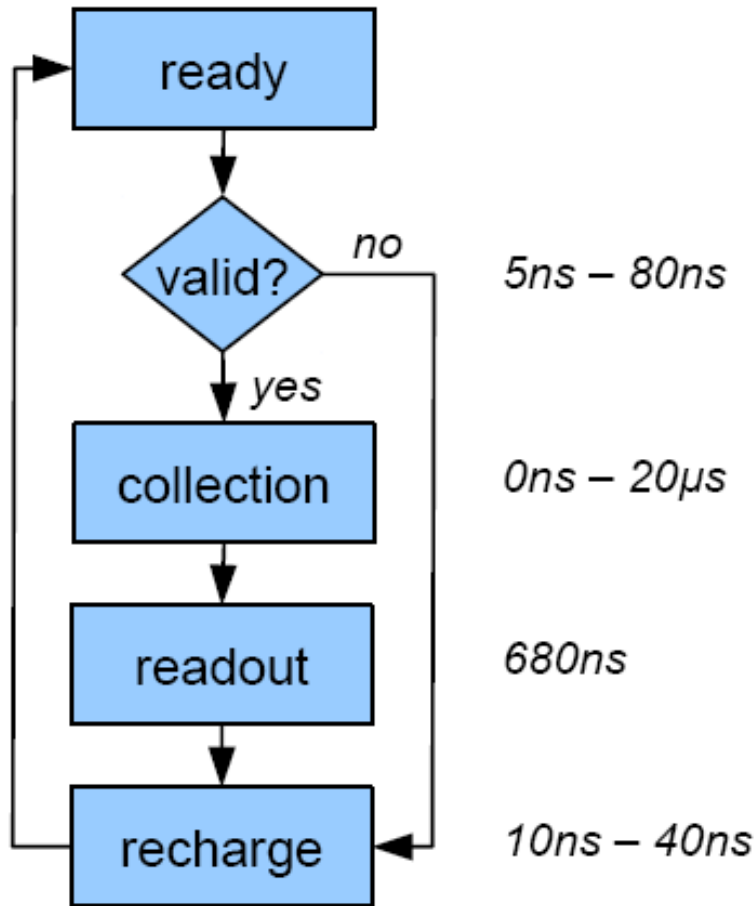
# Digital SiPM: Principle



# Digital SiPM: Principle

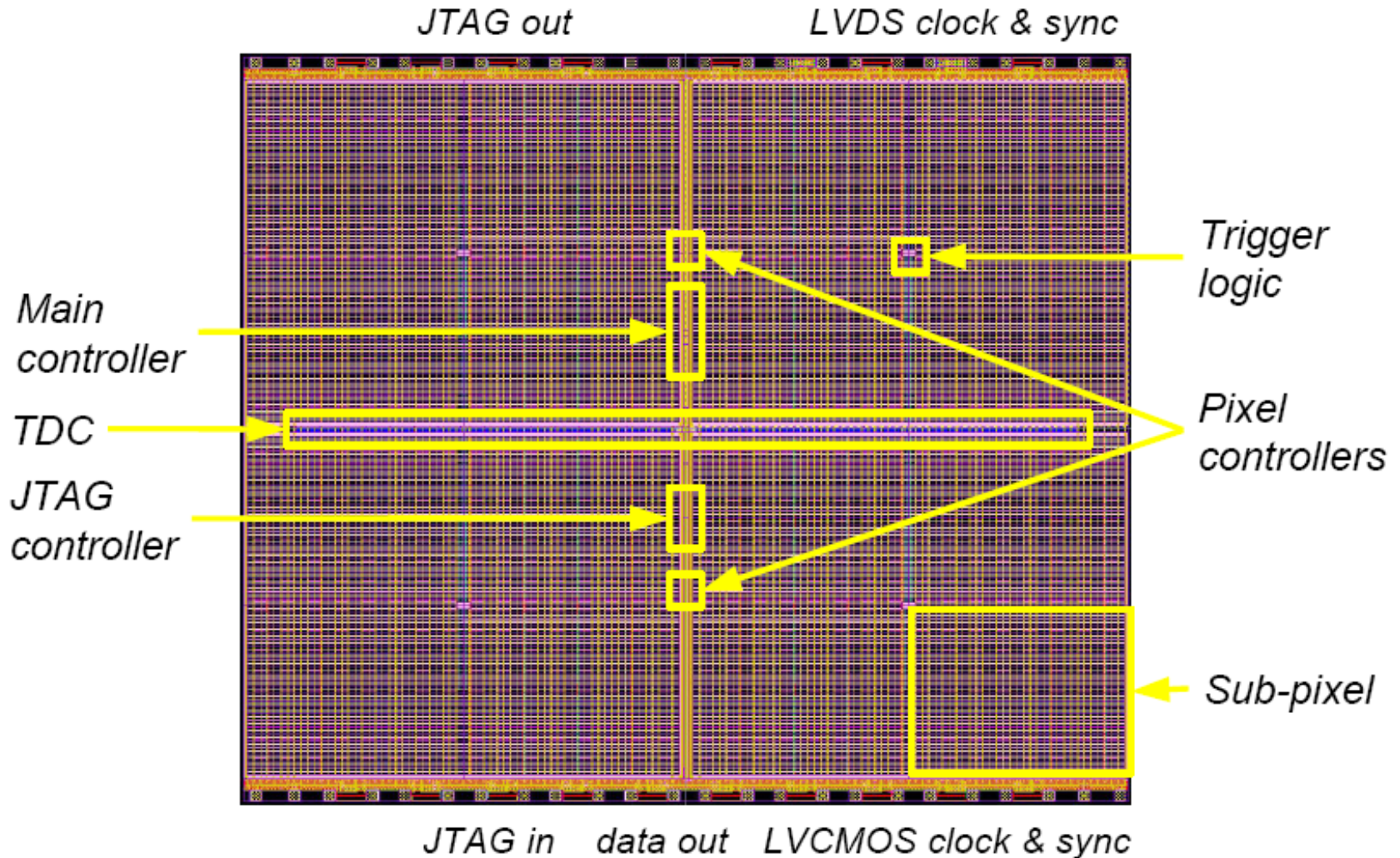


# Digital SiPM: Acquisition sequence (example)



- 200MHz (5ns) system clock
- Variable light collection time up to 20µs
- 20ns min. dark count recovery
- dark counts => sensor dead-time
- data output parallel to the acquisition of the next event (no dead time)
- Trigger at 1, ≥2, ≥3 and ≥4 photons
- Validate at ≥4 ... ≥64 photons (possible to bypass event validation completely)

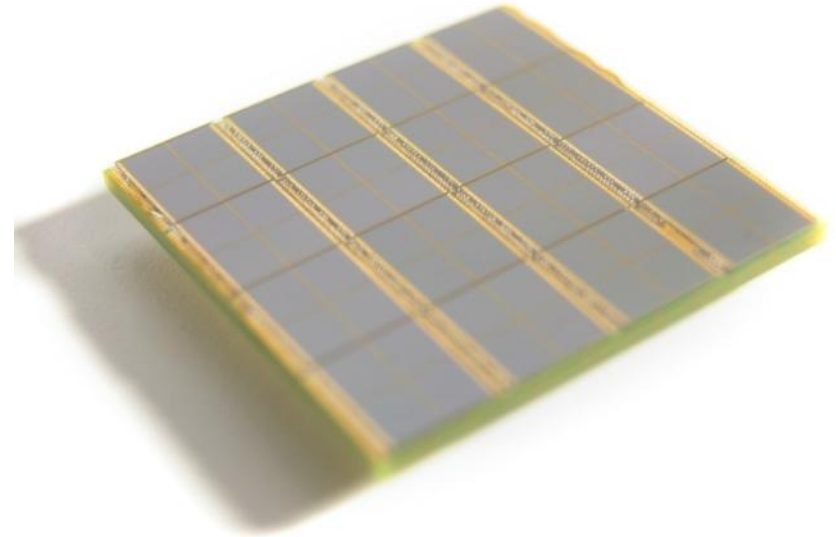
# PDPC Digital SiPM: architecture (die)



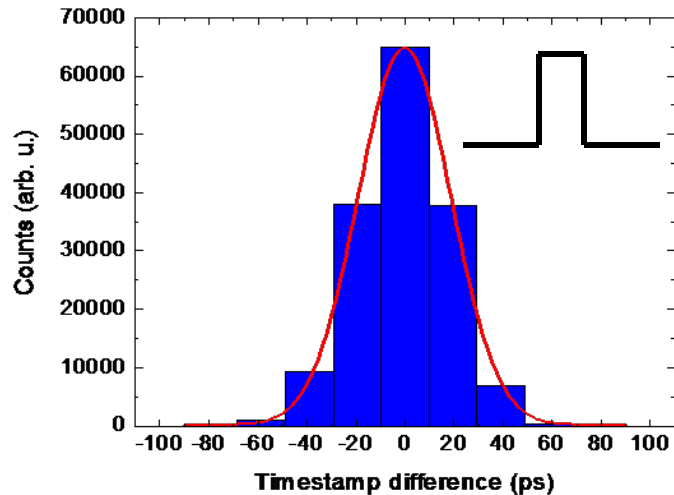
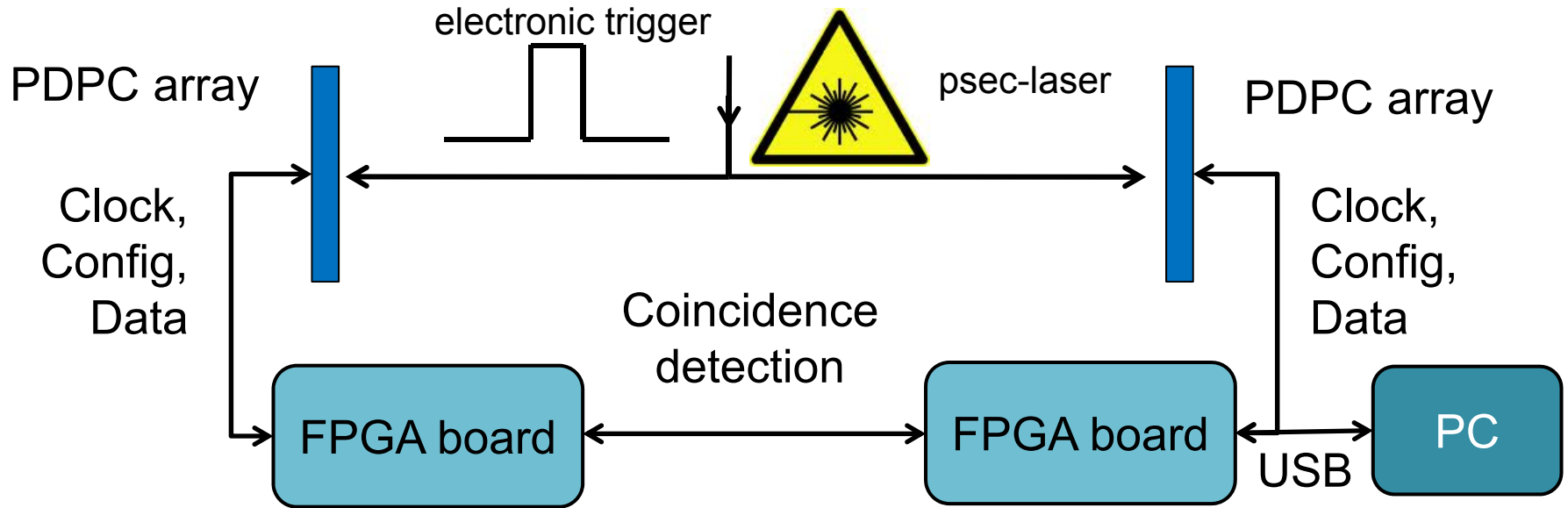
# ***Digital SiPM array (tile)***

## *Features*

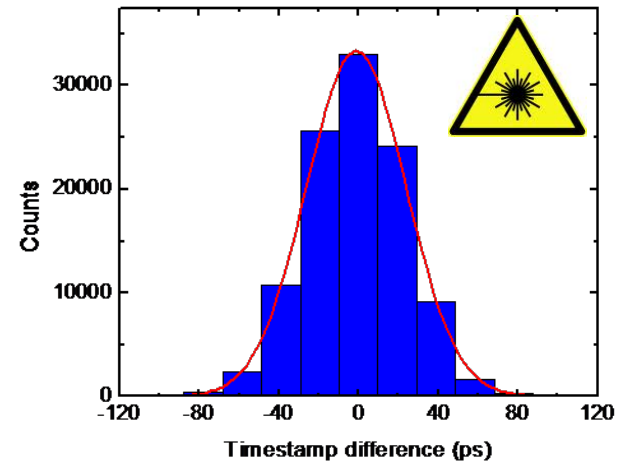
- 8 x 8 digital SiPMs (on 4 x 4 chips)
- 6400 diodes (cells) per pixel
- ~ 11 cm<sup>2</sup>
- 4-side tiling possible
- Inputs
  - 1.8 V, 3.3 V, 30 V
  - JTAG (test and configuration)
  - 200 MHz reference clock
  - External trigger input
- Outputs
  - 100 MHz serial data (photon count, timestamp)
  - Event detect trigger



# PDPC dSiPM: intrinsic timing resolution

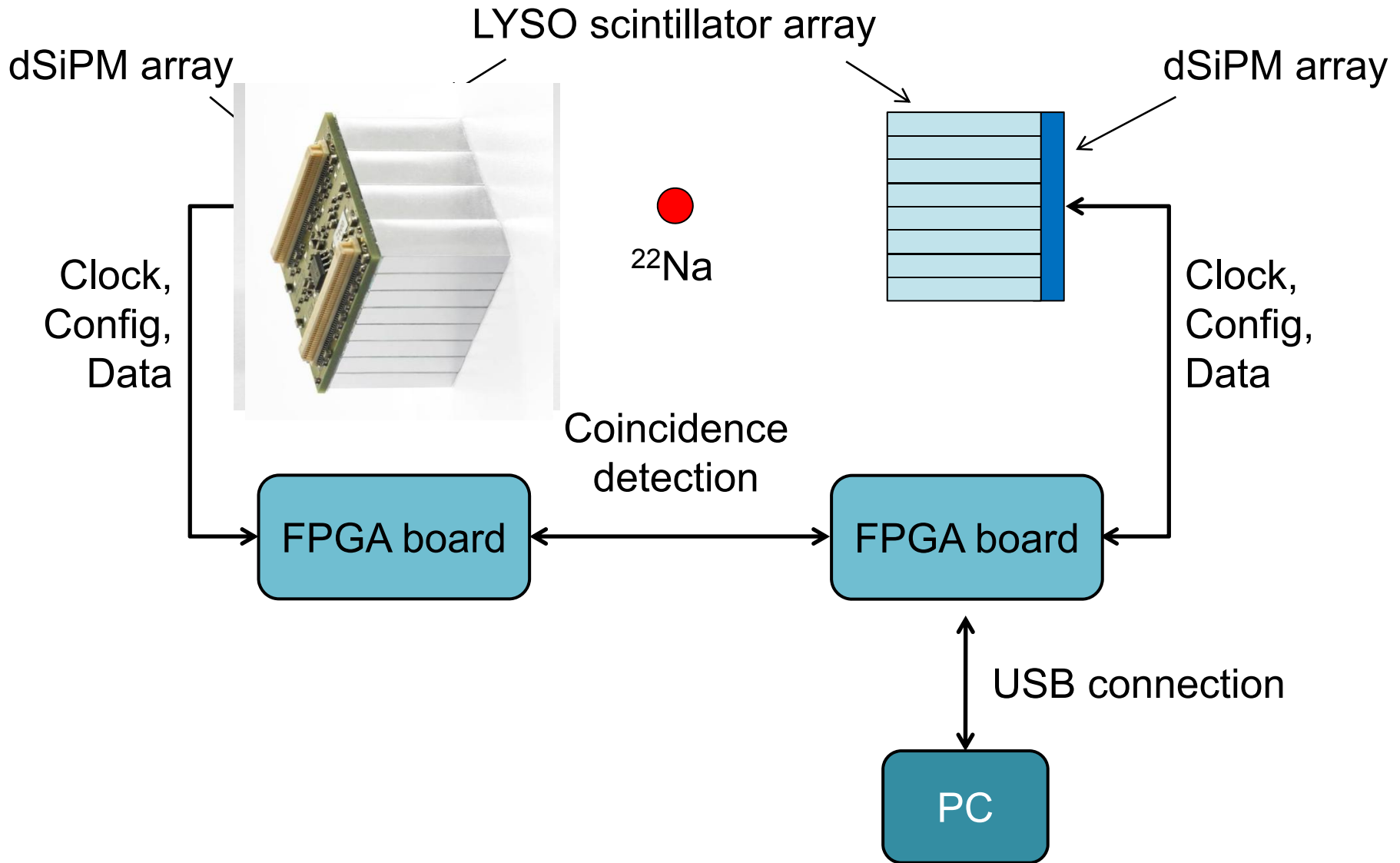


Timing jitter: **44 ps FWHM**

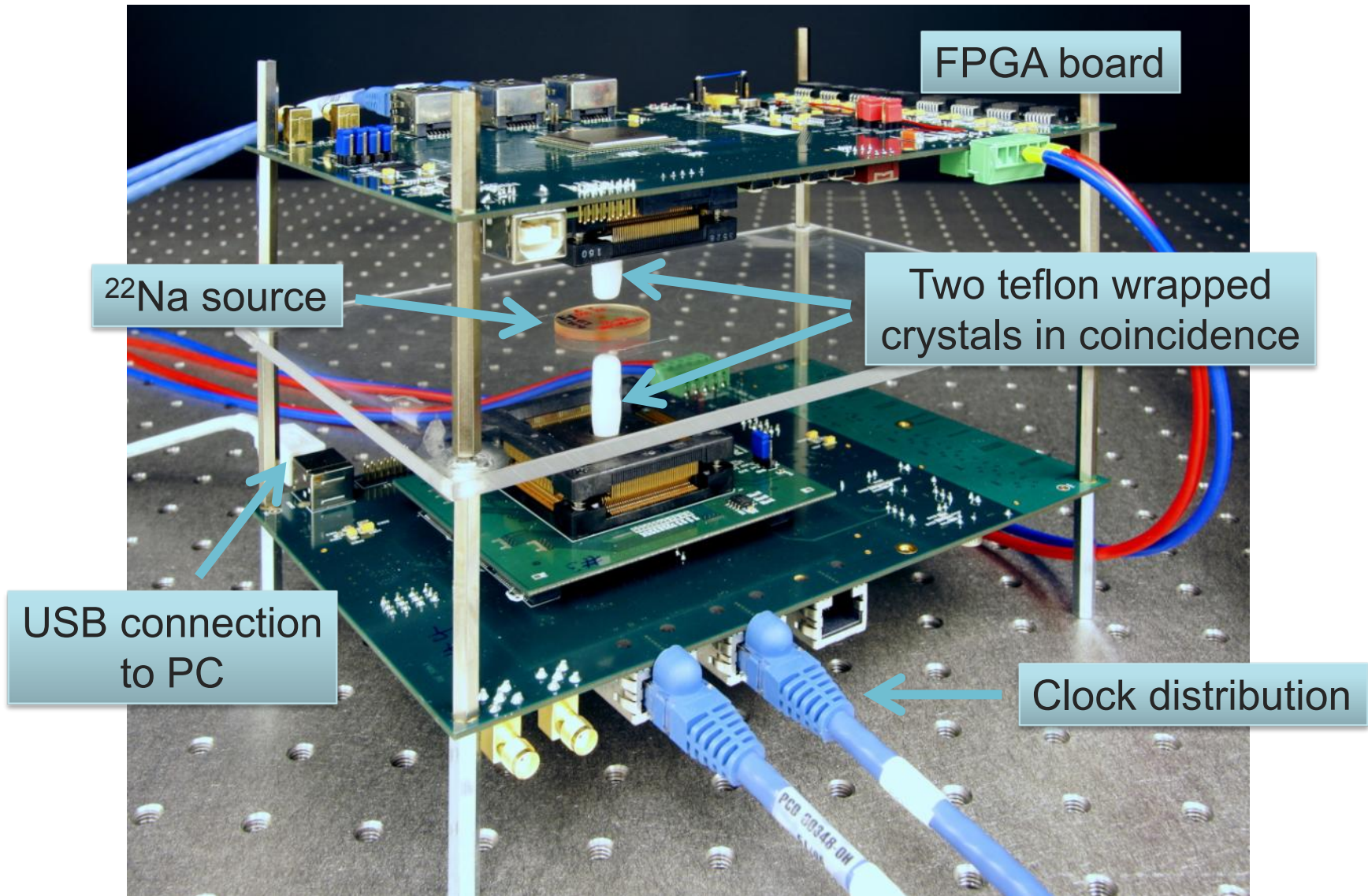


**59 ps FWHM**

# PDPC scintillator coincidence setup



# PDPC test setup (available Q2-11)

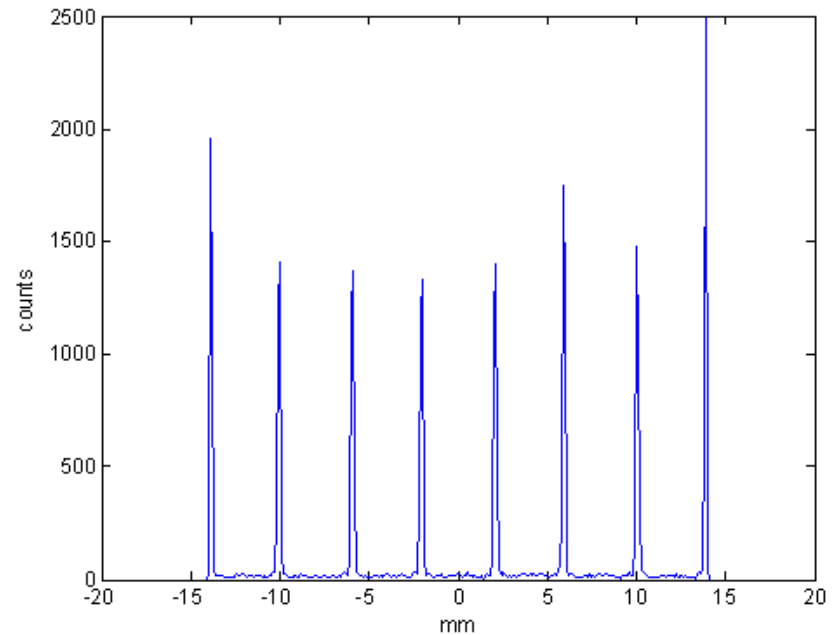
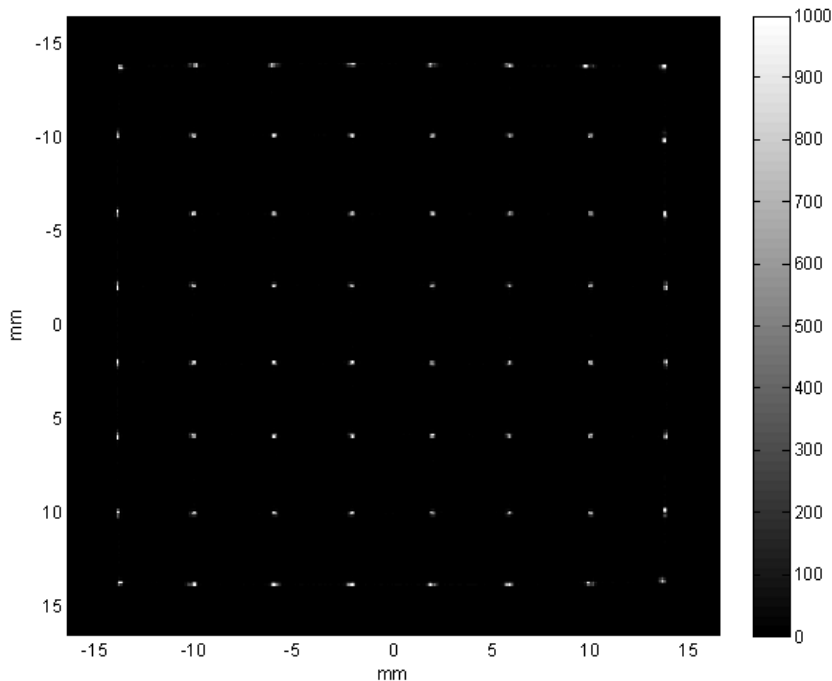




# ***PDPC dSiPM: Scintillator readout (1:1 coupling)***

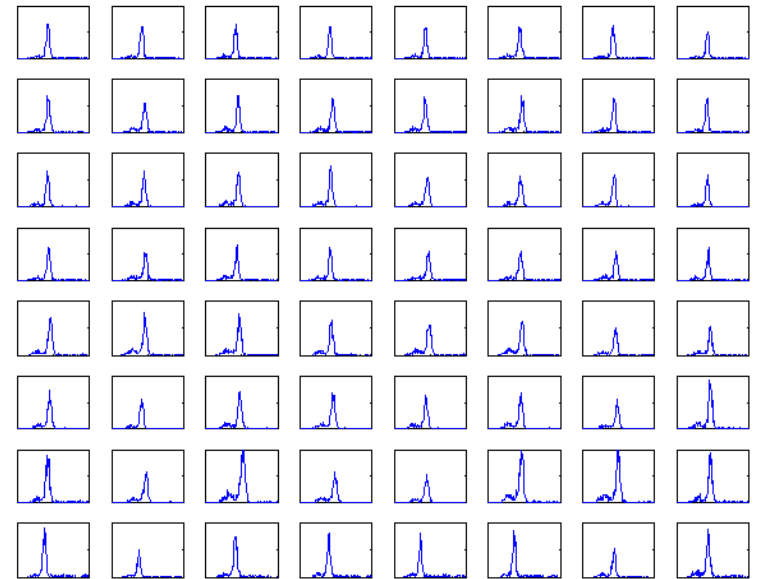
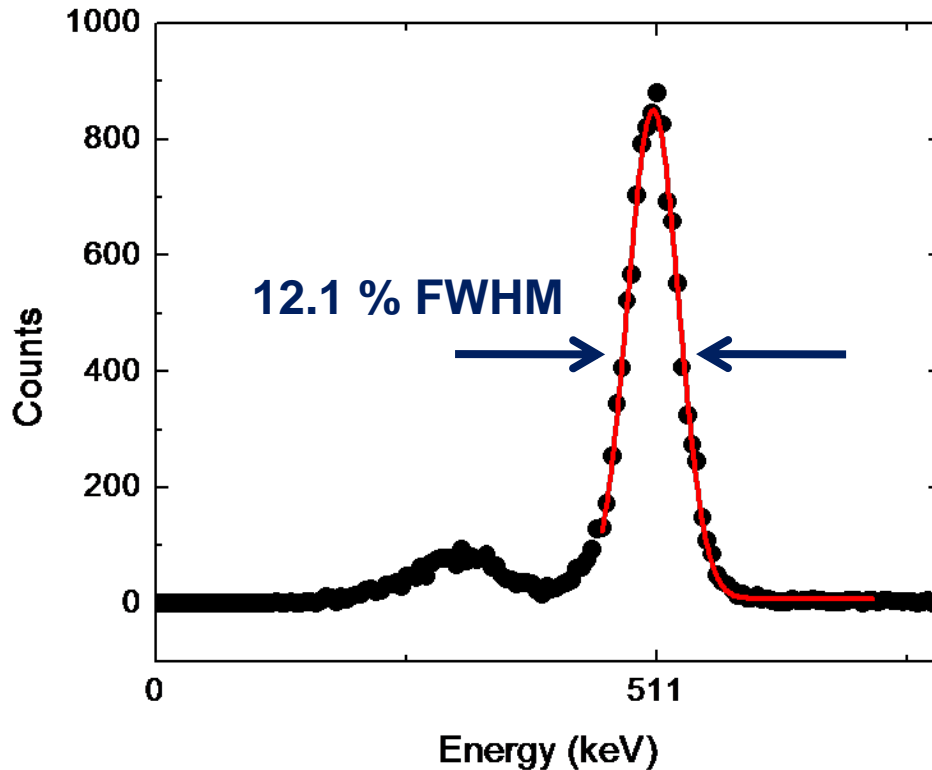
## ***Floodmap***

- LYSO array, 8 x 8 crystals, 4 mm x 4 mm pitch, 22 mm length



# ***PDPC Digital SiPM***

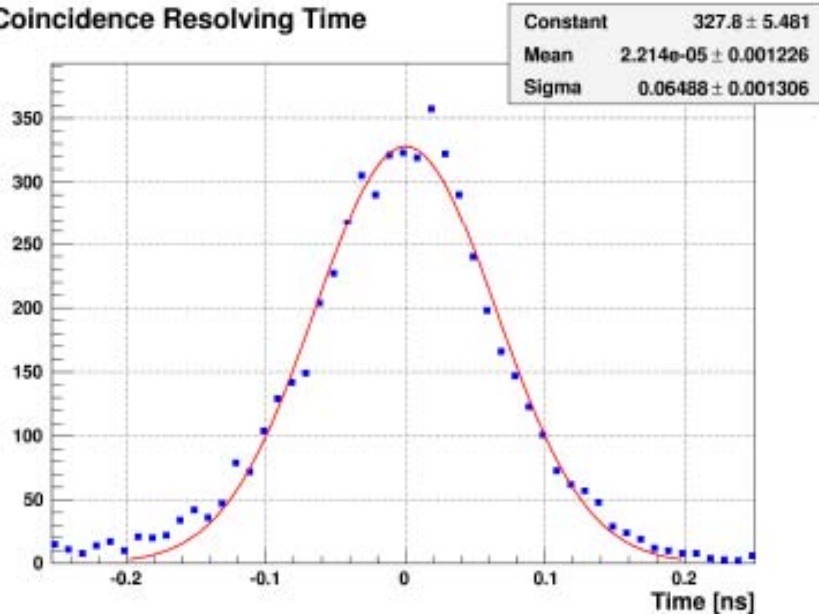
## *Energy resolution*



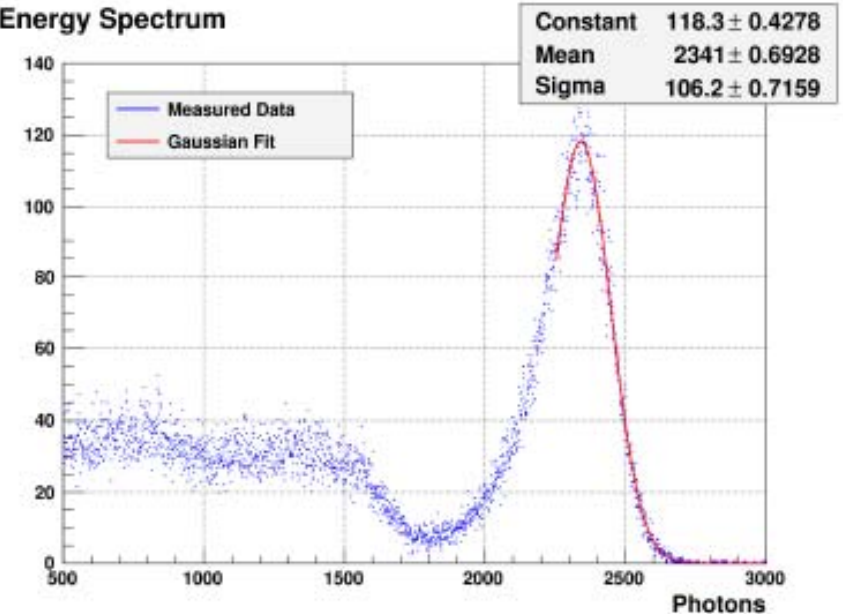
- LYSO array, 8 x 8 crystals, 4 mm x 4 mm pitch, 22 mm length
- Saturation was corrected for

# PDPC dSiPM: Coincidence timing resolution

Coincidence Resolving Time



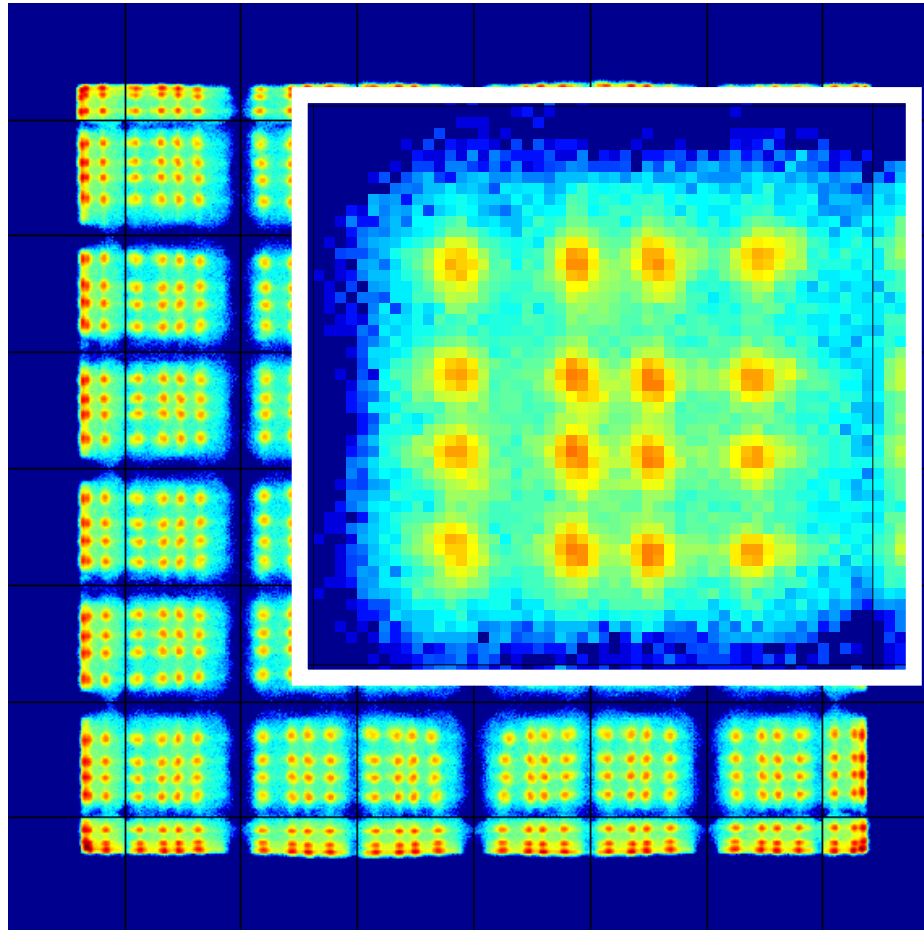
Energy Spectrum



- 3X3x5 mm<sup>3</sup> LYSO in coincidence, <sup>22</sup>Na source
- Time resolution in coincidence: **153ps** FWHM
- Energy resolution (excluding escape peak): **10.7%**
- Excess voltage 3.3V, 98.5% active cells
- Room temperature (31°C board temperature, not stabilized)

# *PDPC dSiPM: Small crystal readout*

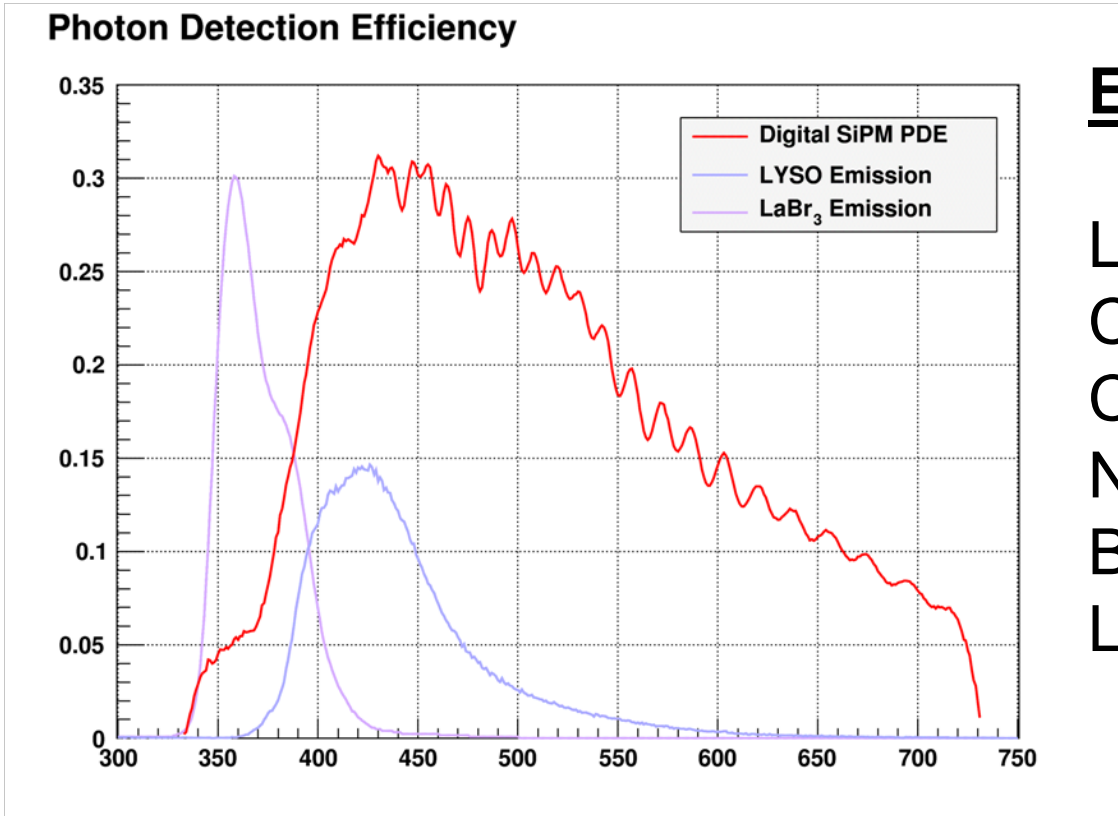
LYSO array, 30 x 30 crystals, 1 mm x 1 mm pitch, 10 mm length



Log scale

Data analysis by P. Düppenbecker, Philips Research

# ***PDPC dSiPM: Spectral sensitivity***



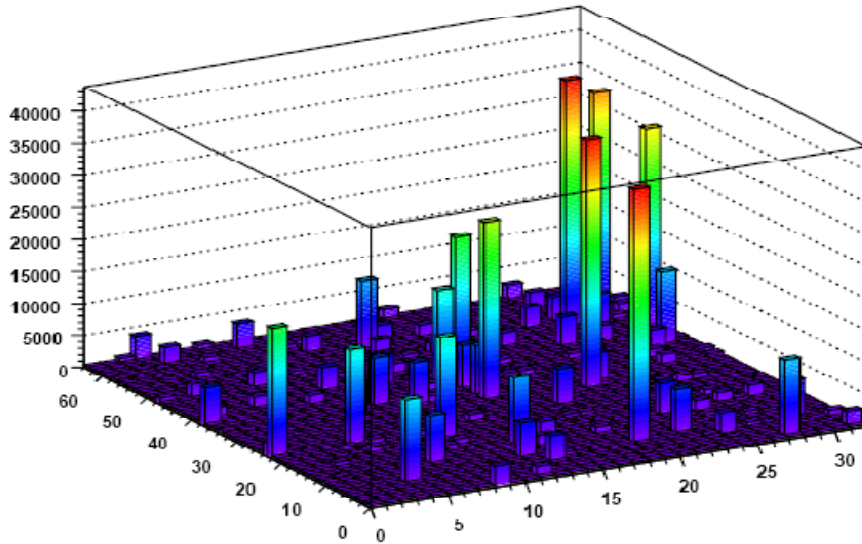
## **Effective PDE:**

LYSO(Ce)	25.9%
CsI(Na)	23.7%
CsI(Tl)	20.5%
NaI(Tl)	24.2%
BGO	24.2%
LaBr <sub>3</sub> (Ce)	9.6%

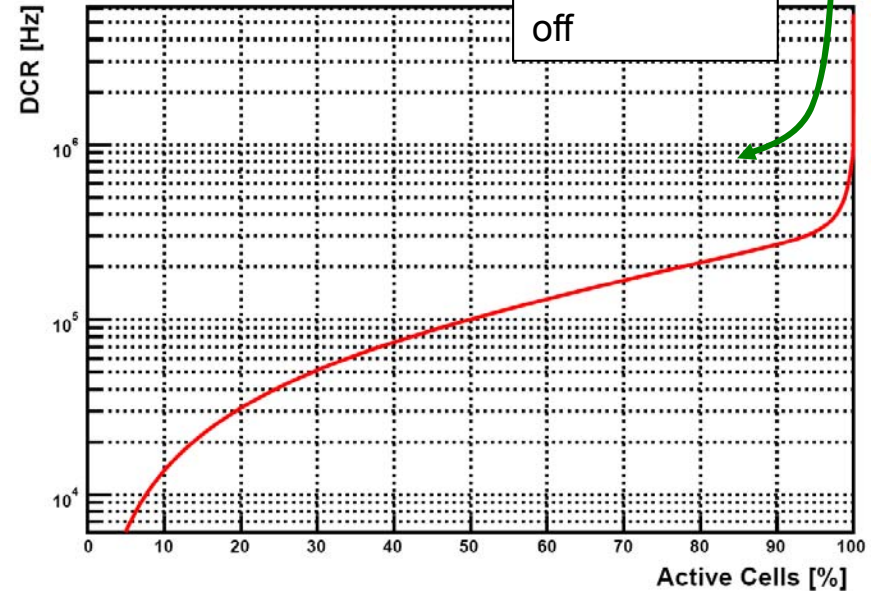
- Peak PDE ~30% at 430nm and 3.3V excess voltage
- Conservative diode design (50 % fill-factor)
- No anti reflection coating used

# PDPC dSiPM: Dark count map

Dark count rate map

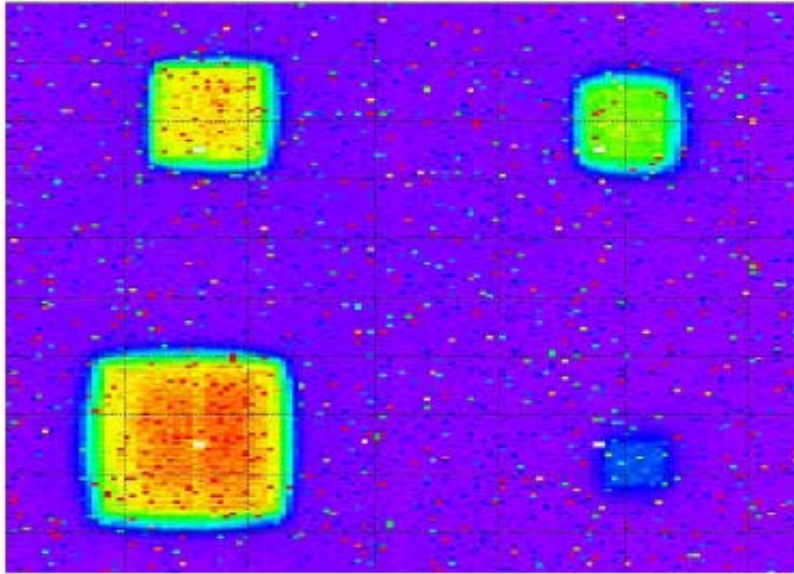


DCR vs. Active Area

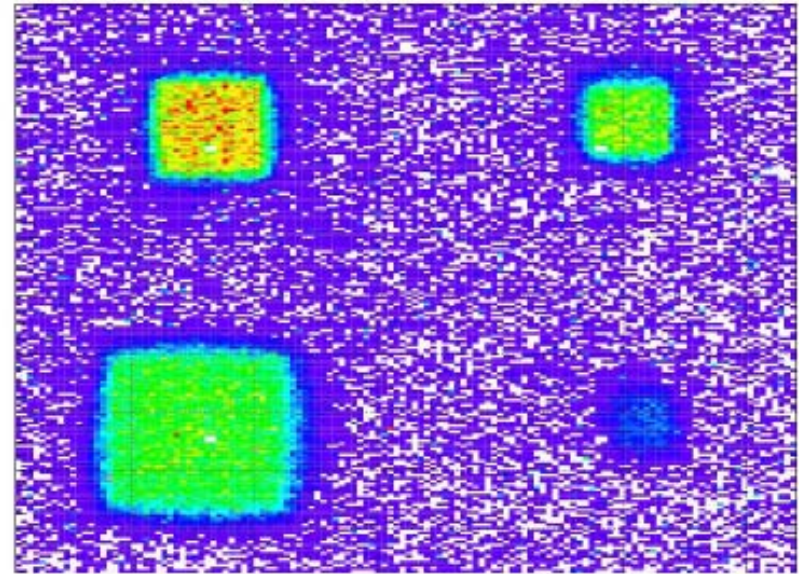


- Dark counts per second at 20°C and 3.3V excess voltage
- ~ 95% good diodes (dark count rate close to average)
- Typical dark count rate at 20°C and 3.3V excess voltage: ~150Hz / diode
- Dark count rate drops to ~1-2Hz per diode at -40°C

# *PDPC dSiPM: slow scan imaging mode*

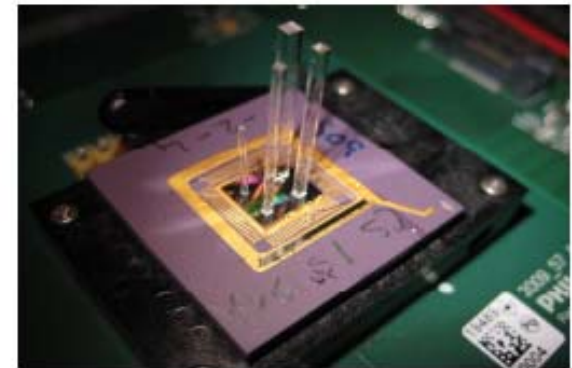


Singles

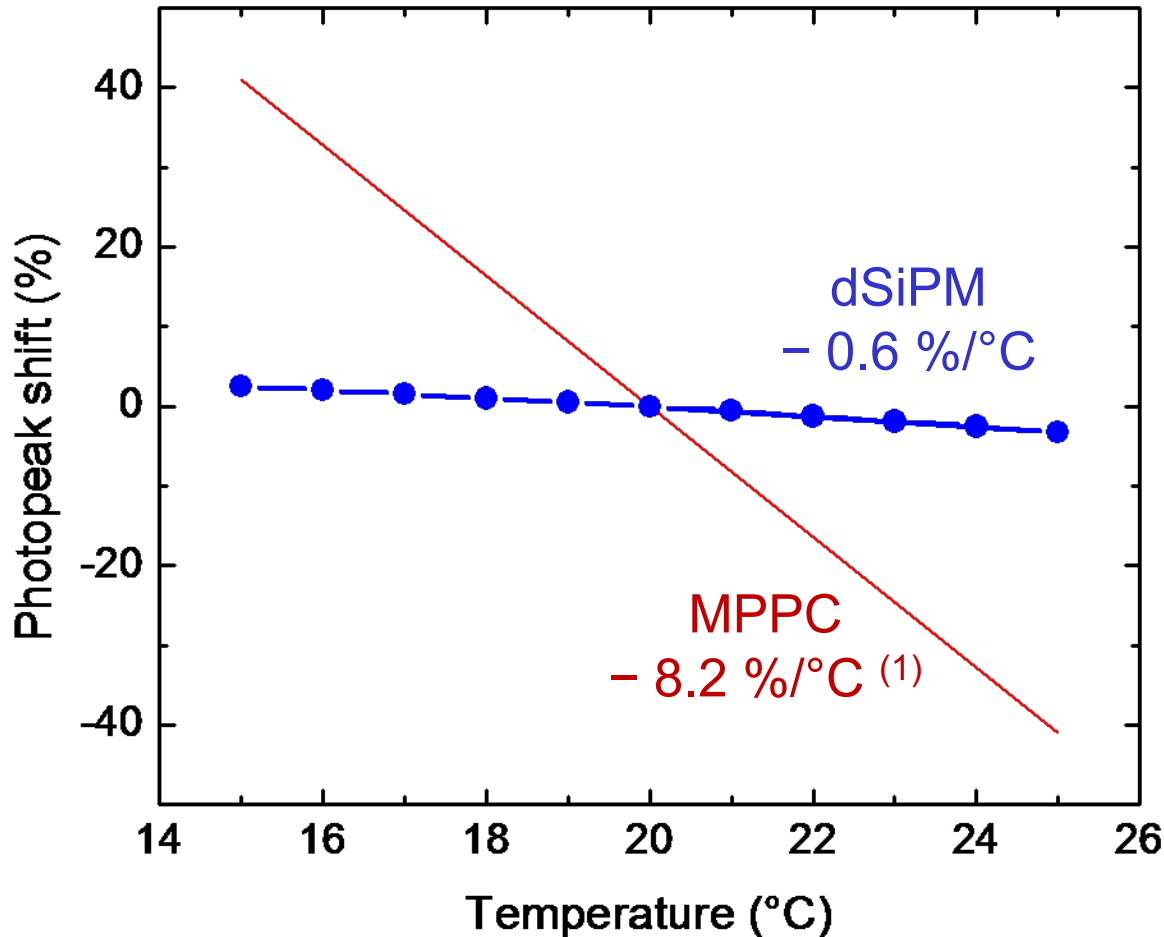


Coincidences

- *Spatial sampling of the light distribution*
- *Similar to dark count map measurement*
- *Dark count map can be used for correction*
- *Alternatively, use coincidence to reduce noise*
- *Potentially useful for light guide design*



# PDPC dSiPM: Temperature dependence



Temperature dependent light output of LYSO:

- 0.2 %/°C <sup>(2)</sup>

- 0.45 %/°C <sup>(3)</sup>

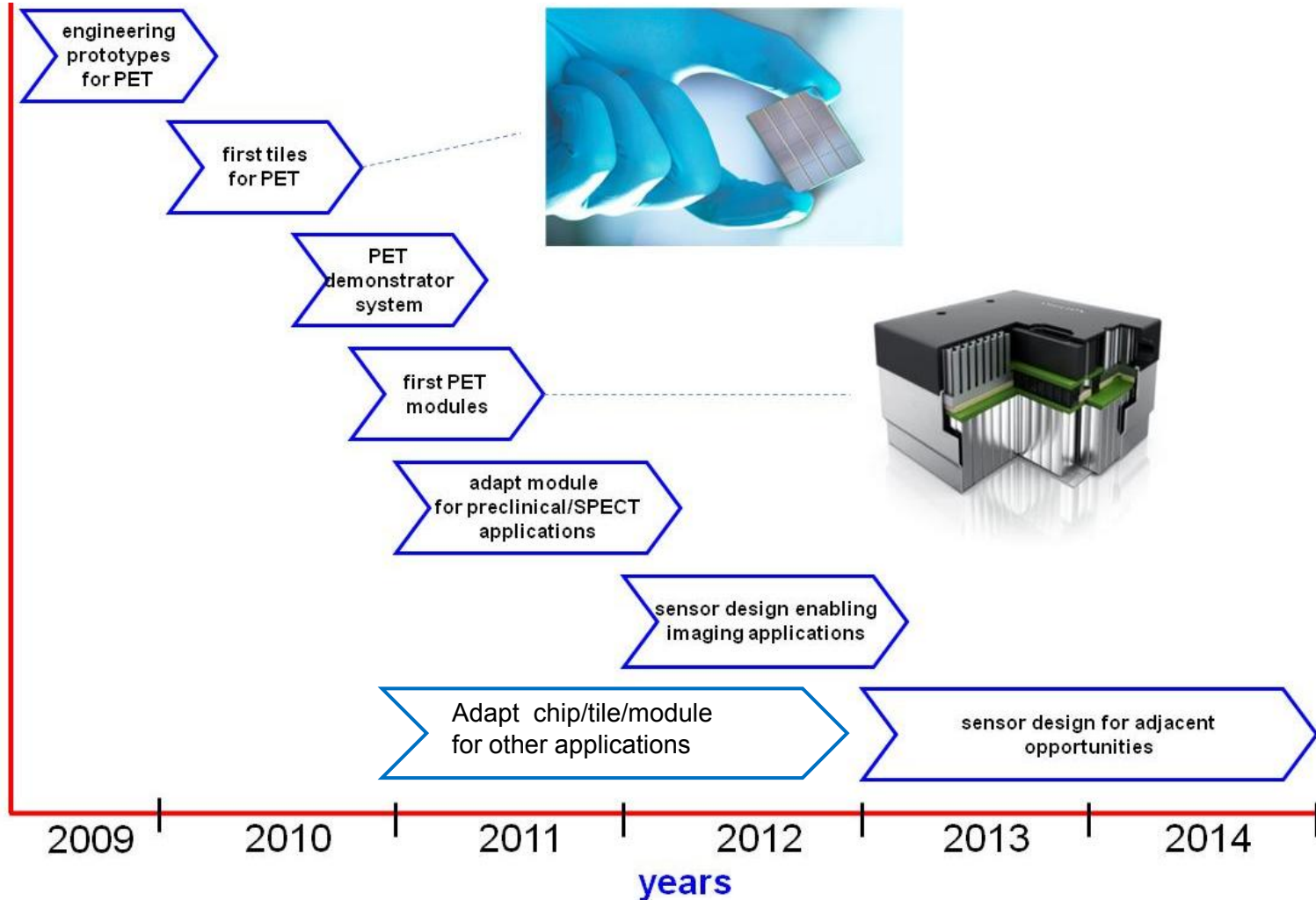
<sup>1</sup> K. Burr et al, Nuclear Science Symposium Conference Record, N18-2, 2007

<sup>2</sup> R. Mao et al, IEEE Transactions of Nuclear Science, vol. 55, 2008

<sup>3</sup> C. Kim, Nuclear Science Symposium Conference Record, M07-113, 2005

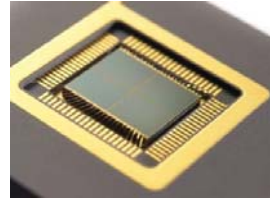


# ***PDPC: Technology Roadmap***



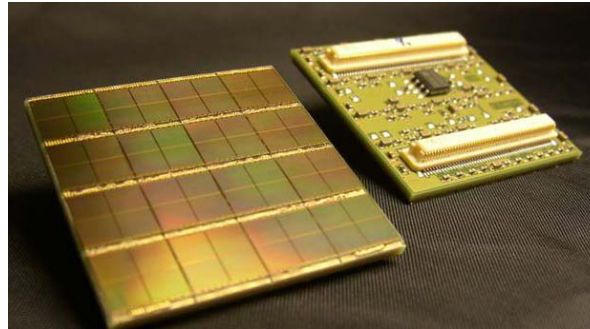
# ***PDPC sensors: simplified electronic design***

**die**  
*(2 x 2 pixel)*



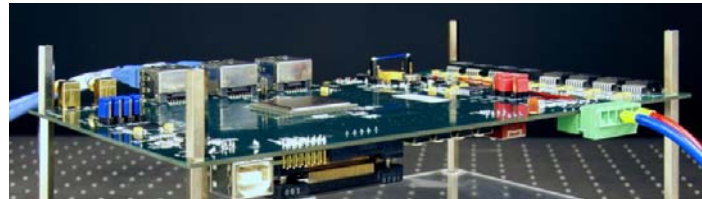
no. of photons/pixel

**tile-PCB**  
*(16 dies + FPGA)*



time stamping  
sorting, control

**module PCB**  
*(n-tiles)*



tile power supply,  
clustering, Anger logic

**processing unit**



e.g. coincidence  
processing

**All digital**

## ***PDPC sensors: Benefits***

### **Application**

#### Speed

- Outstanding timing resolution (e.g. for TOF)

#### Sensitivity

- Lower dark count level (background noise) than analogue systems

#### Robustness

- Low sensitivity to temperature variations
- Insensitive to electromagnetic interference

### **System design**

- Simplified system design (no HV, no analog processing)
- Reduced system costs
- Low voltage operation / Reduced power consumption

